

SuperMOS –TO-252 60V BV_{DSS}, 26mΩ R_{DS(on)}, N-channel MOSFET

1. Description

The NCE6020AK-ES is N-Channel enhancement MOS Field Effect Transistor. Uses advanced technology and design to provide excellent R_{DS(ON)} with low gate charge. Device is suitable for use in DC-DC conversion, power switch and charging circuit. Standard Product NCE6020AK-ES is Pb-free.

2. Features

- 60V, R_{DS(ON)}=26mΩ(TYP.) @V_{GS}=10V
- R_{DS(ON)}=33mΩ(TYP.) @V_{GS}=4.5V
- High density cell design for low R_{DS(on)}
- Material: Halogen free
- Reliable and rugged
- Avalanche Rated
- Low leakage current

3. Applications


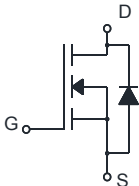
- PWM applications
- Load switch
- Power management in portable/desktop PCs
- DC/DC conversion

100% UIS TESTED!

4. Ordering Information

Part Number	Package	Marking	Material	Packing	Quantity per reel	Flammability Rating	Reel Size
NCE6020AK-ES	TO-252	ES35N06A/LOT	Halogen free	Tape & Reel	2,500 PCS	UL 94V-0	13 inches

5. Pin Configuration and Functions

Pin	Function	Outline	Circuit Diagram
1	Gate		
3	Source		
2	Drain		

6. Specification

Absolute Maximum Rating & Thermal Characteristics

Ratings at 25 °C ambient temperature unless otherwise specified.

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	BV_{DSS}	60	V
Gate-Source Voltage	V_{GS}	± 20	V
Continuous Drain Current	I_D	$T_C=25^\circ C$	20
		$T_C=75^\circ C$	16
Maximum Power Dissipation	P_D	25	W
Pulsed Drain Current	I_{DM}	80	A
Avalanche Current, Single Pulsed ^a	I_{AS}	16	A
Avalanche Energy, Single Pulsed ^a	E_{AS}	16	mJ
Operating Junction Temperature	T_J	150	°C
Lead Temperature	T_L	260	°C
Storage Temperature Range	T_{stg}	-55 to 150	°C

Thermal resistance ratings

Single Operation					
Parameter		Symbol	Typ	Max	Unit
Junction-to-Case Thermal Resistance	Steady State	$R_{\theta JC}$		5	°C/W

Note:

a: $T_J=25^\circ C$, $V_{DD}=60V$, $V_G=10V$, $L=0.3mH$, $R_g=25\Omega$

Electrical Characteristics

At TA = 25°C unless otherwise specified

Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Unit
OFF CHARACTERISTICS						
Drain-to-Source Breakdown Voltage	BV_{DSS}	$V_{GS}=0V, I_D=250\mu A$	60			V
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS}=60V, V_{GS}=0V$			1.0	μA
Gate-to-source Leakage Current	I_{GSS}	$V_{DS}=0V, V_{GS}=\pm 20V$			± 100	nA
ON CHARACTERISTICS						
Gate Threshold Voltage	$V_{GS(TH)}$	$V_{GS}=V_{DS}, I_D=250\mu A$	1.0	1.6	2.5	V
Drain-to-source On-resistance	$R_{DS(on)}$	$V_{GS}=10V, I_D=20A$		26	33	m Ω
		$V_{GS}=4.5V, I_D=10A$		33	45	
Forward Trans conductance	g_{FS}	$V_{DS}=5.0V, I_D=20A$			40	S
CHARGES, CAPACITANCES AND GATE RESISTANCE						
Input Capacitance	C_{ISS}	$V_{GS}=0V, f=1MHz, V_{DS}=25V$		860		pF
Output Capacitance	C_{OSS}			62		
Reverse Transfer Capacitance	C_{RSS}			51		
Total Gate Charge	$Q_{G(TOT)}$	$V_{GS}=10V, V_{DS}=30V, I_D=10A$		20.3		nC
Gate-to-Source Charge	Q_{GS}			3.8		
Gate-to-Drain Charge	Q_{GD}			5.5		
SWITCHING CHARACTERISTICS						
Turn-On Delay Time	$t_{d(ON)}$	$V_{GS}=10V, V_{DS}=30V, I_D=5A, R_G=1.8\Omega$		6		ns
Rise Time	t_r			6		
Turn-Off Delay Time	$t_{d(OFF)}$			19		
Fall Time	t_f			3		
BODY DIODE CHARACTERISTICS						
Forward Voltage	V_{SD}	$V_{GS}=0V, I_S=10A$		0.7	1.5	V

7. Typical Characteristic

Figure 1: Output Characteristics

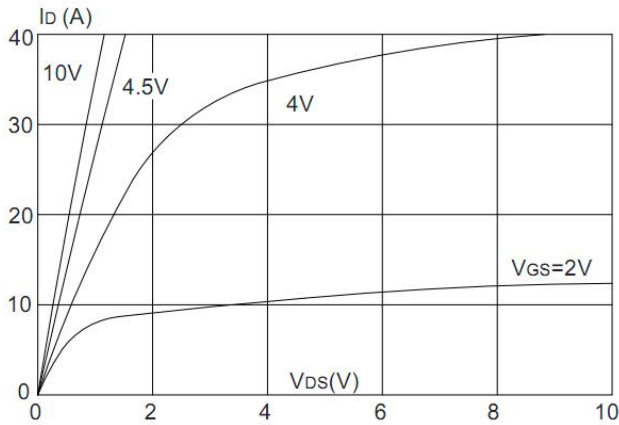


Figure 2: Typical Transfer Characteristics

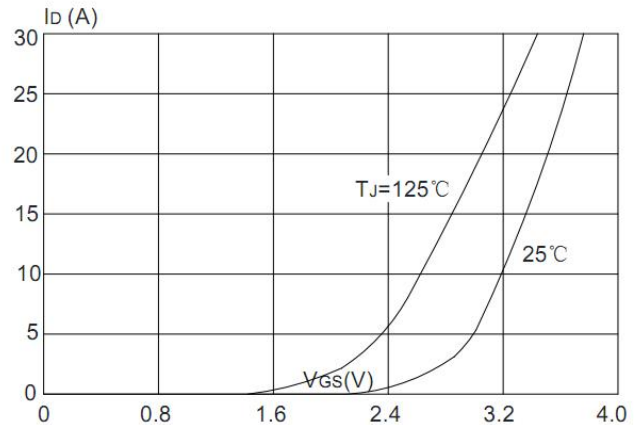


Figure 3: On-resistance vs. Drain Current

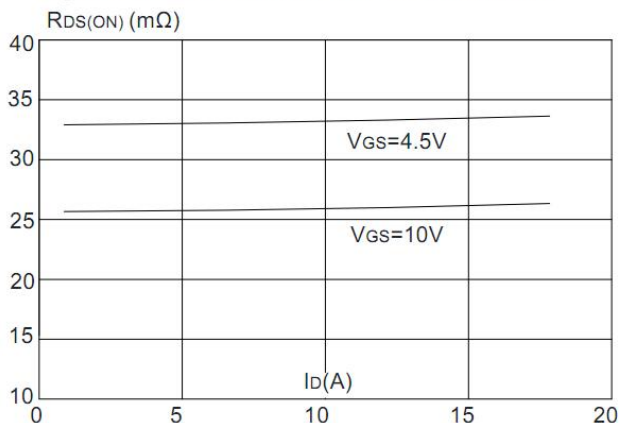


Figure 4: Body Diode Characteristics

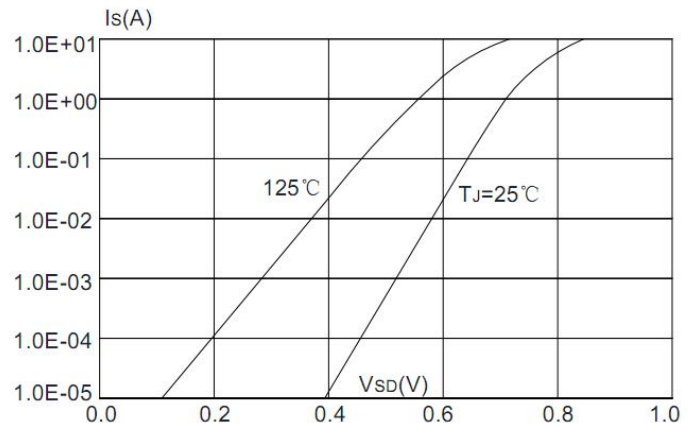


Figure 5: Gate Charge Characteristics

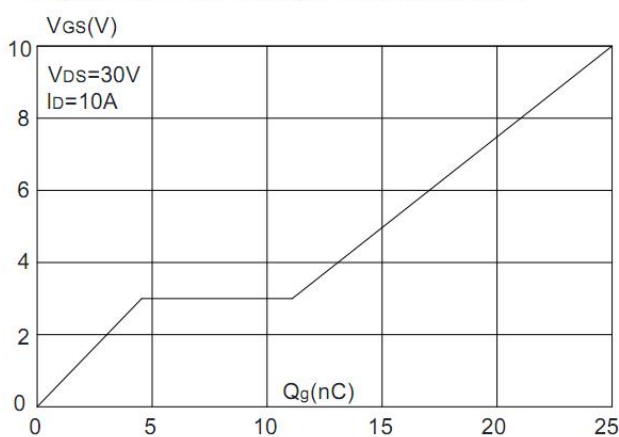


Figure 6: Capacitance Characteristics

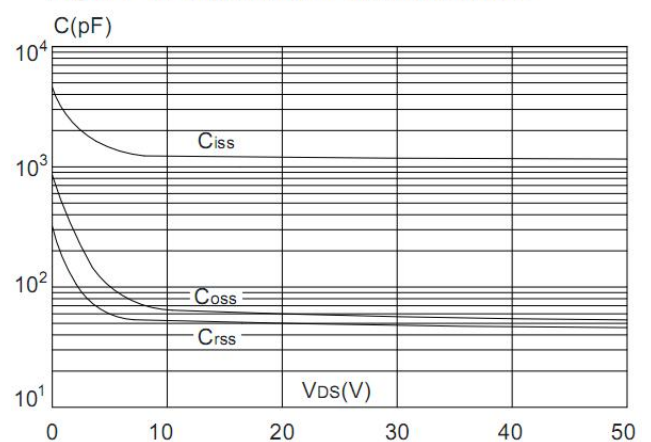


Figure 7: Normalized Breakdown Voltage vs. Junction Temperature

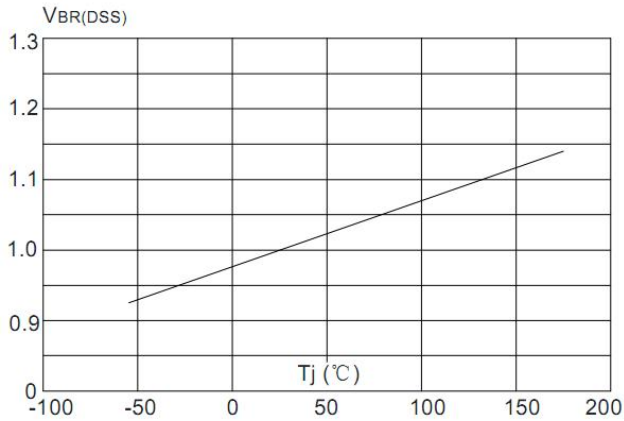


Figure 8: Normalized on Resistance vs. Junction Temperature

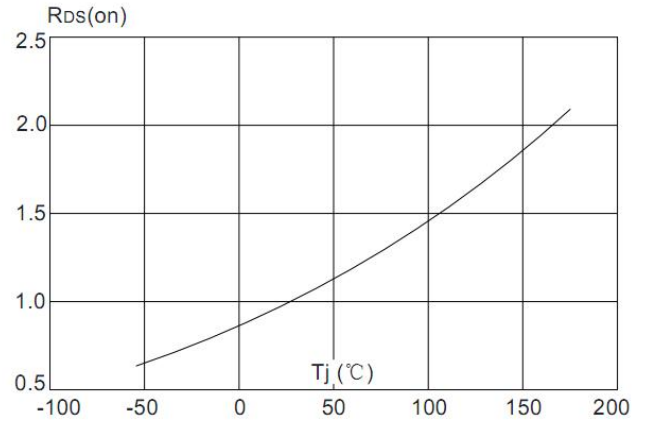


Figure 9: Maximum Safe Operating Area

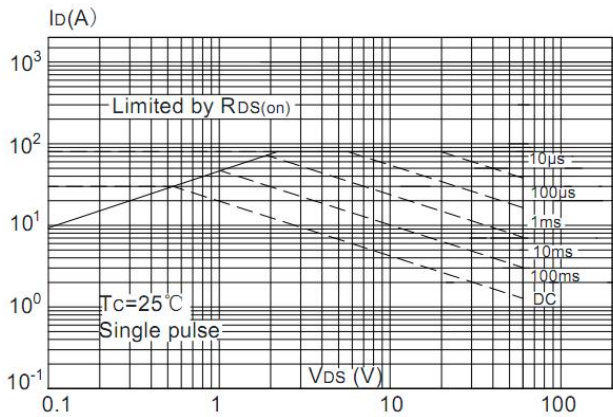


Figure 10: Maximum Continuous Drain Current vs. Case Temperature

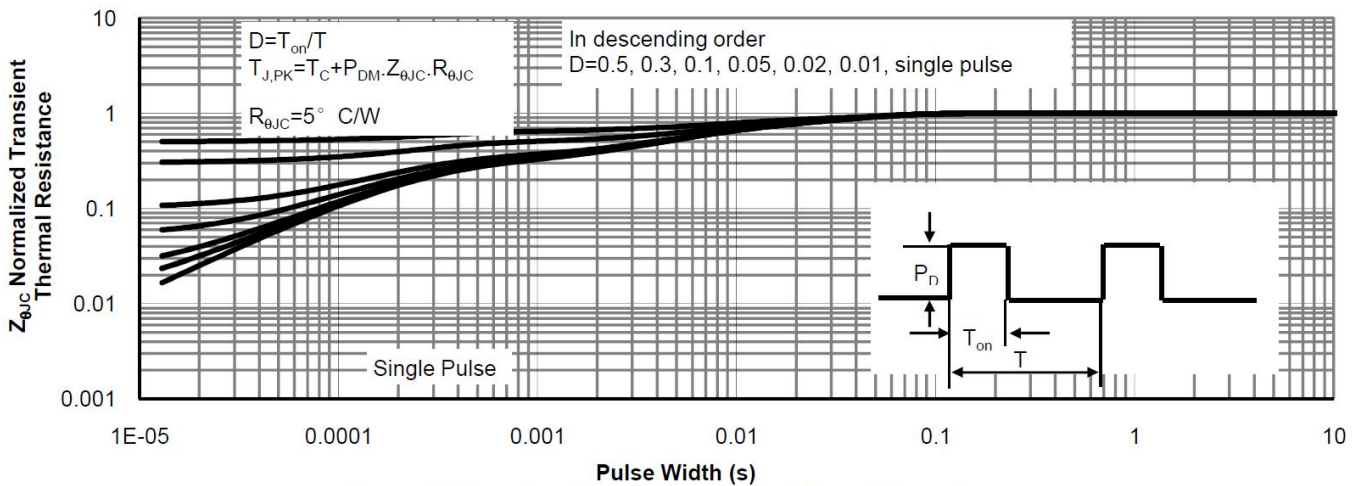
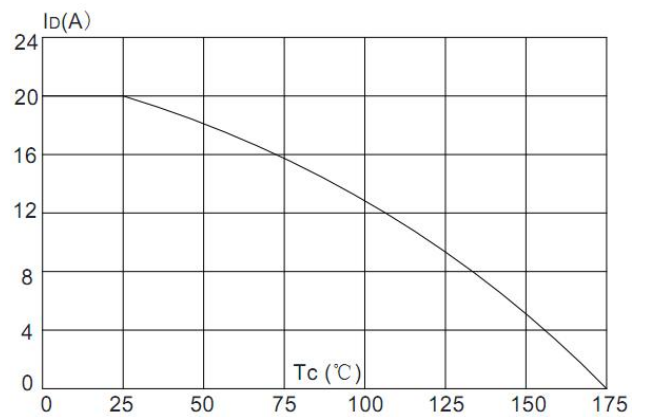
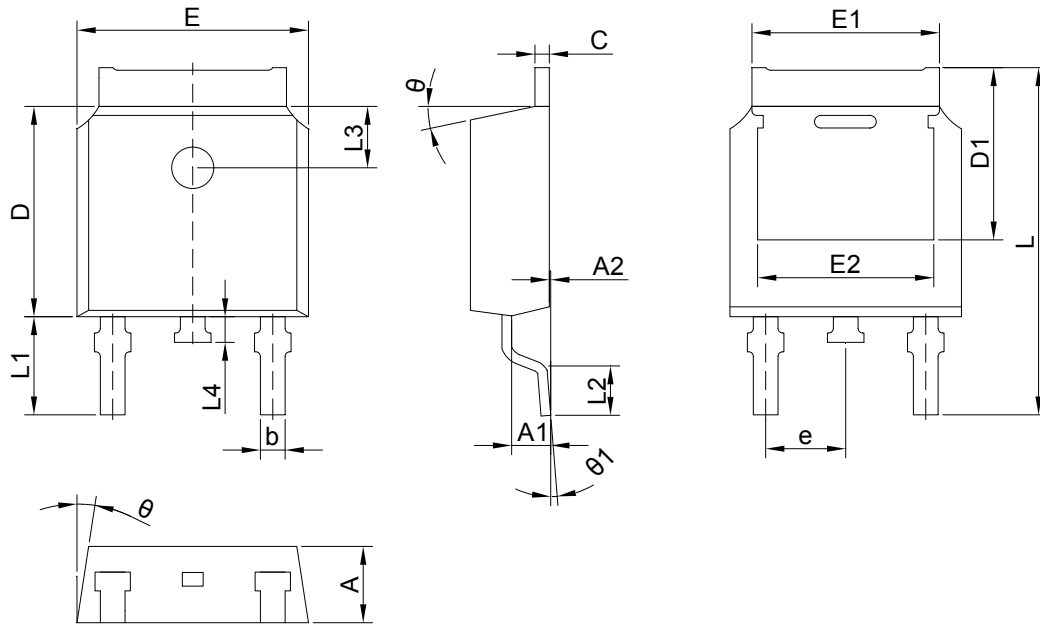


Figure 11: Normalized Maximum Transient Thermal Impedance

8. Dimension (TO-252)



COMMON DIMENSIONS CUNITS MEASURE=MILLIMETER							
SYMBOL	MIN	TYP	MAX	SYMBOL	MIN	TYP	MAX
A	2.10	2.30	2.50	E2	4.63	4.83	5.03
A1	0.97	1.07	1.17	L	9.90	10.10	10.30
A2	0.00	-	0.12	L1	2.74	2.94	3.14
b	0.66	0.76	0.86	L2	1.40	1.50	1.70
C	0.45	0.51	0.60	L3	1.65	1.80	1.95
D	5.90	6.10	6.30	L4	0.60	0.80	1.00
D1	5.10	5.30	5.45	e	2.286 BSC		
E	6.40	6.60	6.80	theta	5°	7°	10°
E1	5.10	5.33	5.45	theta1	0°	-	3°

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